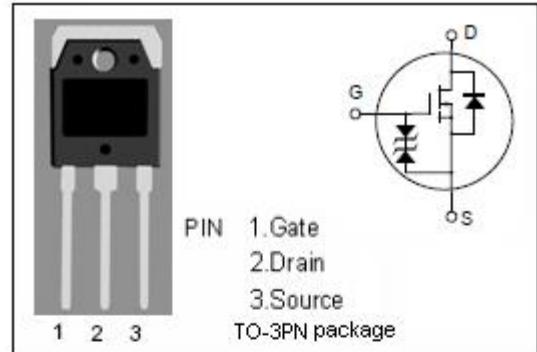


isc N-Channel MOSFET Transistor

2SK1968

DESCRIPTION

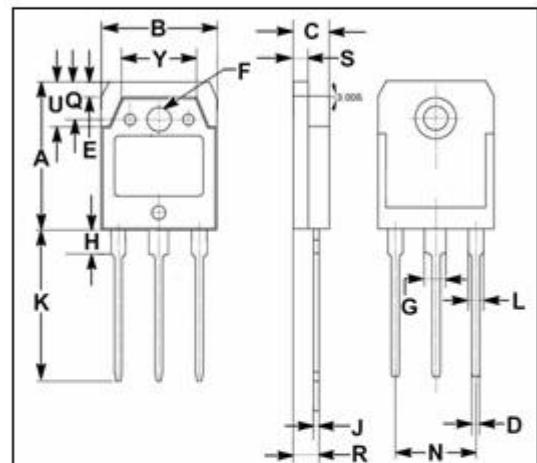
- Drain Current – $I_D=12A$ @ $T_C=25^\circ C$
- Drain Source Voltage-
 - : $V_{DSS}= 600V$ (Min)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Suitable for switching regulator

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	600	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-continuous@ $TC=25^\circ C$	12	A
P_{tot}	Total Dissipation@ $TC=25^\circ C$	100	W
T_j	Max. Operating Junction Temperature	150	°C
T_{stg}	Storage Temperature Range	-55~150	°C



isc N-Channel Mosfet Transistor

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• ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}= 0$; $I_D= 10 \mu\text{A}$	600			V
$V_{(\text{BR})\text{GSS}}$	Gate-Source Breakdown Voltage	$V_{\text{DS}}= 0$; $I_G= 250 \mu\text{A}$	± 30			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}= 10\text{V}$; $I_D= 1\text{mA}$	2		3	V
V_{DF}	Body to drain diode forward voltage	$I_F= 12\text{A}$, $V_{\text{GS}}= 0$		1.1		V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}= 10\text{V}$; $I_D= 6\text{A}$		0.68	0.88	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{\text{GS}}= \pm 25\text{V}$; $V_{\text{DS}}= 0$			± 10	μA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}= 500\text{V}$; $V_{\text{GS}}= 0$			250	μA
C_{iss}	Input capacitance	$V_{\text{DS}}=10\text{V}; V_{\text{GS}}=0\text{V}; f_T=1\text{MHz}$		1800		pF
C_{rss}	Reverse transfer capacitance			60		
C_{oss}	Output capacitance			400		
t_r	Rise time	$V_{\text{GS}}=10\text{V}; I_D=5\text{A}; V_{\text{DD}}=200\text{V}; R_L=6\Omega$		70		ns
t_{on}	Turn-on time			25		
t_f	Fall time			65		
t_{off}	Turn-off time			145		

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